Nanoscale constrictions in superconducting coplanar waveguide resonators

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We report on the design, fabrication, and characterization of superconducting coplanar waveguide resonators with nanoscopic constrictions. By reducing the size of the center line down to 50 nm, the radio frequency currents are concentrated and the magnetic field in its vicinity is increased. The device characteristics are only slightly modified by the constrictions, with changes in resonance frequency lower than 1% and internal quality factors of the same order of magnitude as the original ones. These devices could enable the achievement of higher couplings to small magnetic samples or even to single molecular spins and have applications in circuit quantum electrodynamics, quantum computing, and electron paramagnetic resonance. © 2014 AIP Publishing LLC.

The field of cavity quantum electrodynamics (QED) studies the interaction of photons in resonant cavities with either natural or “artificial” atoms, such as quantum dots and superconducting qubits, having a nonlinear and discrete energy level spectrum.1,2 For applications in spectroscopy and especially quantum information processing, a major goal is to maximize the coupling strength to the spins of donor defects in silicon21 and to flux quantum systems.12–15 Electron spins are attractive due to their usually longer coherence times, as compared with electrical degrees of freedom, which could allow longer storage times for quantum information.2 Strong coupling to single spins or small ensembles of them has not been achieved yet, due to their weaker coupling to the electromagnetic radiation. Achieving this limit would open new possibilities in quantum information and related fields. Artificial molecular magnets, synthesized by chemical methods, are of especial interest as they provide realizations of well-defined and identical qubits and quantum logic gates.16–19 In a previous work,20 it was proposed that strong magnetic coupling could be achieved, even for single molecular magnets, by narrowing the center line of a resonator down to nanometer length scales, as long as the resonator characteristics can be maintained. A similar procedure has been proposed to couple superconducting resonators to the spins of donor defects in silicon21 and to flux qubits.8 In this work, we design, fabricate, and test superconducting CPW resonators with this type of constrictions and show that their characteristics are stable within a relatively broad range of constriction geometries.

Our devices are fabricated on 500 μm thick C-plane sapphire wafers and consist of a 150 nm thick niobium layer deposited by radio frequency (RF) sputtering and then patterned by either photolithography and lift-off or reactive ion etching. Nanoscale constrictions were made at the midpoint of the center line by etching it with a focused beam of Ga ions,22 using a commercial dual beam system. The ionic current was kept below 20 pA to maximize the resolution in the fabrication process and to minimize the Nb thickness, of order 10–15 nm, that is implanted with Ga22,23 Images of these constrictions, as those shown in Fig. 1, were obtained in situ by scanning electron microscopy. The microwave transmission measurements were done using a programmable network analyzer at 4.2 K by mounting the devices on a home-made probe and submerging them in liquid helium.

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The circuits consist of a large 400 μm center line and 200 μm gaps that narrow down to around 14 μm and 7 μm, respectively, after going through gap capacitors. Several types of gap capacitors with a finger design (see Fig. 1) were fabricated to allow for differently coupled systems. The gaps between the fingers are of 4 μm while the finger lengths are of 100 μm. The length of the cavity is chosen to be 44 mm by making the waveguide meander across the surface. Although sapphire has an anisotropic dielectric constant, taking an average value of εr = 10 is sufficient for our circuit calculations. These parameters give a waveguide characteristic impedance Z0 = 50 Ω and an unloaded f0 = 1.5 GHz. The resonances move to higher frequencies (from 1.3 GHz to 1.45 GHz) and have higher Q (from 100 to 30000) the less coupled they are to the feed lines.24 The gap capacitances Cgap have been estimated, as illustrated in Fig. 2, by fitting the transmission S21 vs frequency data with a simple circuit model, which consists of a segment of transmission line with two identical capacitors connected to the input and output ports. They range from 70 to 5 fF, of the order of magnitude of values reported in the literature.5

After the devices were characterized, the center line was narrowed down from about 10 μm to minimum widths w of 50 nm along distances δ of up to 50 μm (see Fig. 1). Once the constrictions are made, special care must be taken both with the device manipulation and with the scanning electron microscope imaging, since electrostatic buildup and discharge can easily destroy the nanowires. The present study uses two series of three identical resonators. In each series, we make constrictions varying either δ or w and keeping the other constant. The first series has 100 nm wide constrictions and lengths of 1 μm, 5 μm, and 15 μm. Similarly, the second series keeps a constant δ = 1 μm while w is varied through 300 nm, 100 nm, and 50 nm. Other geometries, such as loop constrictions, can also be obtained as we show in Fig. 1(c). The performances of these devices are analyzed by comparing values of f0, Q and maximum transmission (in linear scale), respectively. In this particular case, the original parameters were f0 = 1.378 GHz and Q = 2700 while Δf0/f0 = −0.25%, ΔQ/Q = −22.7%, and ΔS21/S21 = −36%. Thick solid lines are least square fits made with the circuit model shown in (b). The presence of a constriction can be taken into account by introducing two effective lump elements Lk and Rk, that account, respectively, for the reduced f0 and the enhancement of electromagnetic losses. (c) Variation of resonance parameters for 100 nm wide constrictions of varying lengths (with original values of f0 ≥ 1.35 GHz and Q ≥ 800). (d) Variation of resonance parameters for 1 μm long constrictions of varying widths (with original values of f0 ≥ 1.31 GHz and Q ≥ 250).
are from transmission measurements \((S_{21}, S_{12})\), the same behavior can be seen in the reflection signals \((S_{11}, S_{22})\).

The decrease of \(f_0\), of order 1\%, likely results from the enhancement of the inductance at the constriction. A simple approach is to model the constriction by a region of length \(\delta\) and effective inductance per unit length, \(l'\), larger than its value \(l\) outside this region. As it is described in detail in Ref. 24, this effect makes the center line effectively longer for the propagation of RF currents and leads to a close to linear decrease of \(f_0\) with increasing \(\delta\)

\[
\frac{\Delta f_0}{f_0} \approx -\frac{\delta}{L} \left( l' - l \right).
\]

(1)

The experimental data shown in Fig. 2(c) are compatible with \(l'/l = 10.9\). The decrease of \(Q\) and \(S_{21}\) indicate that the constriction introduces some extra losses into the system. This is confirmed by the stronger relative variation seen in \(Q_{\text{int}}\). The constriction constitutes a defect for the propagation of electromagnetic radiation and therefore might enhance reflection to the source. As shown in Fig. 2, the experimental results can be accounted for by a circuit model with two additional lumped elements, an inductance \(L_A\) that accounts for changes of \(f_0\), and a resistance \(R_A\) that accounts for \(\Delta Q\). From fits such as those shown in Fig. 2(a), we find \(L_A\) to lie in the range of a few tens pH, increasing with \(\delta\) as expected from the above considerations, whereas the effective resistance \(R_A\) is of the order of a few m\(\Omega\)’s and fairly independent of \(\delta\). Despite these additional losses, \(Q\) remains mainly limited by the coupling capacitors \(C_e\) for all devices studied in this work (see Fig. 1 in Ref. 24). These results show therefore that the fabrication of narrow constrictions does not preclude the attainment of \(Q_{\text{int}}\) values well above \(10^4\).

Another difference observed in resonators with constrictions is the power dependence of the resonances. Figure 3 shows the transmission through a 100 nm wide and 1 \(\mu\)m long constriction at different excitation powers and for the first three cavity modes. The fundamental mode (Fig. 3(b)) and the second harmonic (Fig. 3(d)) break down when power is increased. This effect can be explained by noting that, since both the fundamental mode and second harmonic have a standing wave with a current maximum at the center (as shown by Fig. 3(a)) where the cross section has been drastically reduced, the constriction can eventually become resistive. By contrast, we find no such effect in the resonance associated with the first harmonic, since there is almost zero current flowing through the constriction for this mode. These qualitative arguments can be made quantitative by comparing the current density at which the resonances break down to the critical current of superconducting niobium. The current flowing through the nanowire can be estimated by applying the definition of \(Q\) and formulas for the equivalent RLC circuit for the resonator.\(^5\) The following expression gives the current amplitude in the resonator:

\[
I = \sqrt{\frac{2Q_{\text{loss}}}{Z_0}}.
\]

(2)

where \(P_{\text{loss}}\) is the power loss from the resonator (dissipated or lost to the feed lines). From the maximum RF power for which the resonance shown in Fig. 3 remains stable, we get a critical current density \(j_c\) \(~1.4(1) \times 10^7\) A cm\(^{-2}\) (corresponding to about \(9 \times 10^9\) photons stored in the cavity), which is of the order of magnitude of that found for niobium thin films.\(^25\) Experiments performed on resonators with 50 nm wide constrictions show a similar power dependence and give \(j_c\) \(~1.0(3) \times 10^7\) A cm\(^{-2}\).\(^24\) These results suggest that the implantation of Ga at the constriction edges, which is consubstantial to focussed ion beam lithography, does not dramatically affect the superconductivity of Nb. They also evidence that the current is forced to flow through the constrictions and that its density, thus also the RF magnetic field, is being locally enhanced.

![Diagram](image-url)
In order to explore such enhancement in a more direct manner, we locally measured, by means of magnetic force microscopy (MFM), the magnetic field generated by a current flowing via one constriction. A 1 μm long by 100 nm wide constriction was fabricated out of a 100 nm thick gold layer deposited on sapphire. The circuit was then mounted on the MFM stage and connected to a direct current source at room temperature. MFM images of the constriction area were measured while a 2.1 mA current was flowing through it. The resulting topographic and magnetic phase images are shown in Fig. 4. These images show a clear magnetic signal (a magnetic phase contrast of Δφ = 0.26° from maximum to minimum) in the constriction area and a negligible signal (indistinguishable from the background) in the wider areas of the circuit. Also, the current was reversed three times during the image acquisition. Each time, a sharp contrast change was observed in the phase image, thus showing that the signal must be magnetic in origin and due to the circulating current. We observe a constant background signal probably due to an electrostatic potential difference between the metallized and non-metallized areas. If greater precision was needed, this background could be filtered out using schemes similar to those detailed in Ref. 26 where electric potential nulling was used.

We conclude that the fabrication of nanoscopic constrictions in the center line of coplanar superconducting resonators provides a simple and efficient method to locally concentrate the RF magnetic field, with a minor cost in terms of quality factor. Although the resonator frequencies explored in this work are relatively low (1.3–1.4 GHz), there is no reason why this method should not also apply to higher frequencies. Numerical simulations show that the magnetic coupling to individual spins located in the close neighborhood of such constrictions is enhanced by nearly two orders of magnitude, reaching values of order 0.1 MHz for some single molecule magnets. These devices could potentially be used to develop high sensitivity spectrometers for the characterization of nanoscopic magnetic samples and, provided that sufficiently long spin decoherence times are attained, to achieve strong coupling to individual magnetic qubits.

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24See supplementary material at http://dx.doi.org/10.1063/1.4899141 for details on the loaded Q-factor, a simple model to estimate the dependence of the resonant frequency on the constriction properties, and the power dependence of a 50 nm resonator.